



SOD1F1 THRU SOD1F7

Reverse Voltage - 50 to 1000 Volts Forward Current - 1.0 Ampere

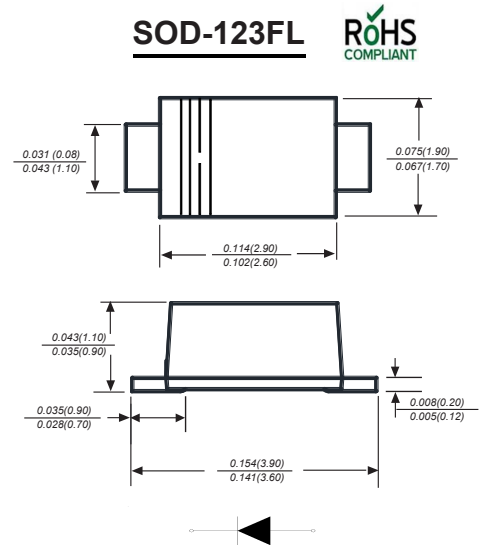
SURFACE MOUNT GENERAL PURPOSE SILICON RECTIFIER

Features

- ◆ Glass passivated device
- ◆ Ideal for surface mounted applications
- ◆ Low reverse leakage
- ◆ Metallurgically bonded construction
- ◆ High temperature soldering guaranteed:
250°C/10 seconds, 0.375" (9.5mm) lead length,
5 lbs. (2.3kg) tension

Mechanical Data

Case: JEDEC UOD-123FL molded plastic body
 Terminals: Solderable per MIL-STD-750, Method 2026A
 Polarity: Polarity symbol marking on body
 Mounting Position: Any
 Weight: 0.0067 ounce, 0.02 grams



Maximum Ratings And Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

Parameter	SYMBOLS	SOD1F1	SOD1F2	SOD1F3	SOD1F4	SOD1F5	SOD1F6	SOD1F7	UNITS
Marking Code		MDD F1	MDD F2	MDD F3	MDD F4	MDD F5	MDD F6	MDD F7	
Maximum repetitive peak reverse voltage	V_{RMM}	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum average forward rectified current at TL (see fig. 1)	$I_{(AV)}$	1.0							A
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	30							A
Maximum instantaneous forward voltage at 1.0A	V_F	1.3							V
Maximum DC reverse current TA=25°C at rated DC blocking voltage TA=125°C	I_R	5 100							mA
Typical junction capacitance (NOTE 1)	C_J	15							pF
Maximum Reverse Recovery Time	t_{rr}	150				250	500		ns
Typical thermal resistance (NOTE 2)	$R_{\theta JA}$	85.0							°C/W
Operating junction temperature range	T_J	-55 to +125							°C
Storage temperature range	T_{STG}	-55 to +150							°C

Note: 1. Measured at 1.0MHz and applied reverse voltage of 4.0V D.C.
 2. P.C.B. mounted with 2.0" X 2.0" (5 X 5 cm) copper pad areas.
 3. The typical data above is for reference only.



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Typical Characteristics

Fig.1 Forward Current Derating Curve

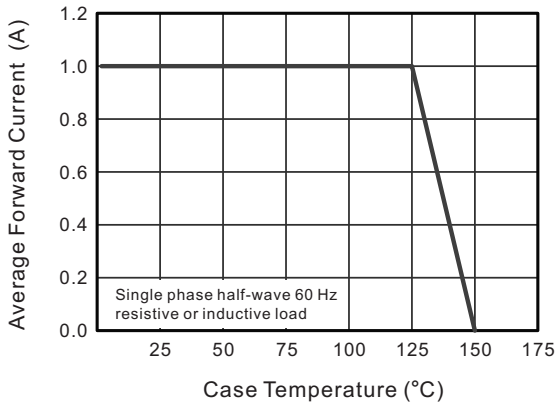


Fig.2 Typical Reverse Characteristics

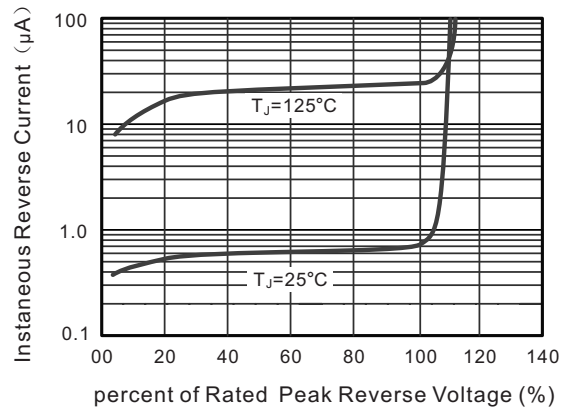


Fig.3 Typical Instantaneous Forward Characteristics

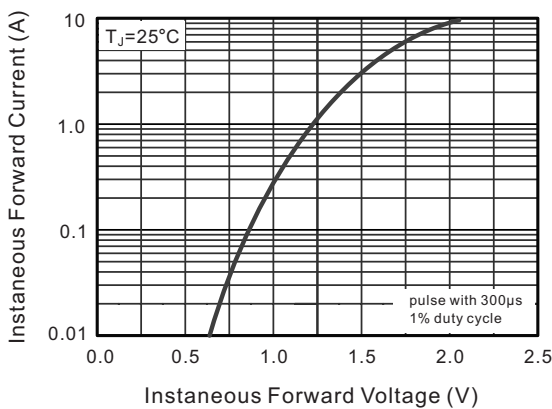


Fig.4 Typical Junction Capacitance

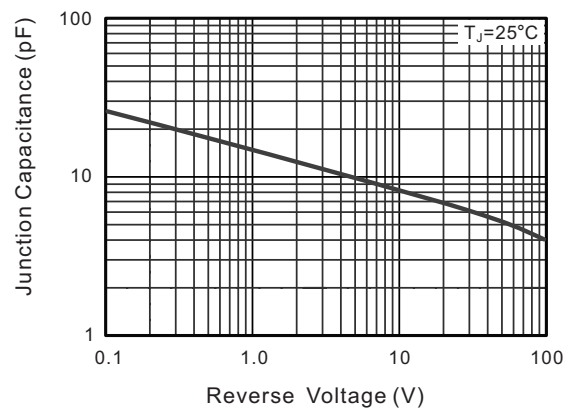
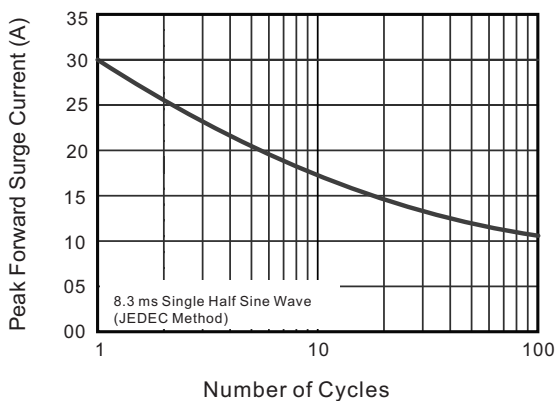


Fig.5 Maximum Non-Repetitive Peak Forward Surge Current



The curve above is for reference only.



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Packing information



unit:mm

Item	Symbol	Tolerance	SOD-123FL
Carrier width	A	0.1	2.1
Carrier length	B	0.1	4.0
Carrier depth	C	0.1	1.60
Sprocket hole	d	0.05	1.55
7" Reel outside diameter	D	2.0	178.00
7" Reel inner diameter	D1	min	50.0
Feed hole diameter	D2	0.5	13.00
Sprocket hole position	E	0.1	1.75
Punch hole position	F	0.1	3.50
Punch hole pitch	P	0.1	4.00
Sprocket hole pitch	P0	0.1	4.00
Embossment center	P1	0.1	2.00
Overall tape thickness	T	0.1	0.25
Tape width	W	0.3	8.15
Reel width	W1	1.0	10.5

Note: Devices are packed in accordance with EIA standard RS-481-A and specifications listed above.

Reel packing

PACKAGE	REEL SIZE	REEL (pcs)	COMPONENT SPACING (m/m)	BOX (pcs)	INNER BOX (m/m)	REEL DIA, (m/m)	CARTON SIZE (m/m)	CARTON (pcs)	APPROX. GROSS WEIGHT (kg)
SOD-123FL	7"	3,000	4.0	45,000	210*208*203	178	430*430*235	180,000	9.0

Suggested Pad Layout



Symbol	Unit (mm)	Unit (inch)
A	1.2	0.047
B	1.2	0.047
C	3.2	0.126
D	2	0.079
E	4.4	0.173

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